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FAIRCHILD SEMICONDUCTOR®

November 2013

FQPF2N70

N-Channel QFET® MOSFET

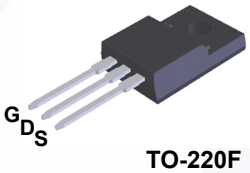
700 V, 2.0 A, 6.3 Ω

Description

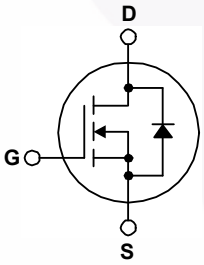
This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power factor correction (PFC), and electronic lamp ballasts.

Features

- 2.0 A, 700 V, $R_{DS(on)}$ = 6.3 Ω (Max.) @ V_{GS} = 10 V, I_D = 1.0 A
- Low Gate Charge (Typ. 9 nC)
- Low Crss (Typ. 5 pF)
- 100% Avalanche Tested



TO-220F



Absolute Maximum Ratings

T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQPF2N70	Unit
V_{DSS}	Drain-Source Voltage		700	V
I_D	Drain Current	- Continuous (T_C = 25°C)	2.0*	A
		- Continuous (T_C = 100°C)	1.3*	A
I_{DM}	Drain Current	- Pulsed (Note 1)	8.0*	A
V_{GSS}	Gate-Source Voltage		± 30	V
E_{AS}	Single Pulsed Avalanche Energy (Note 2)		140	mJ
I_{AR}	Avalanche Current (Note 1)		2.0	A
E_{AR}	Repetitive Avalanche Energy (Note 1)		2.8	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5	V/ns
P_D	Power Dissipation	(T_C = 25°C)	28	W
		- Derate Above 25°C	0.22	W/°C
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds		300	°C

*Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FQPF2N70	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	4.46	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	

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Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQPF2N70	FQPF2N70	TO-220F	Tube	N/A	N/A	50 units

Electrical Characteristics

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA	700	--	--	V
ΔBV_{DSS} / ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	--	0.4	--	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 700 V, V_{GS} = 0 V	--	--	10	μA
		V_{DS} = 560 V, T_C = 125°C	--	--	100	μA
I_{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = 30 V, V_{DS} = 0 V	--	--	100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = -30 V, V_{DS} = 0 V	--	--	-100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = 250 μA	3.0	--	5.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	V_{GS} = 10 V, I_D = 1.0 A	--	5.0	6.3	Ω
g_{FS}	Forward Transconductance	V_{DS} = 50 V, I_D = 1.0 A	--	2.45	--	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V, f = 1.0 MHz	--	270	350	pF
C_{oss}	Output Capacitance		--	38	50	pF
C_{rss}	Reverse Transfer Capacitance		--	5	7	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 350 V, I_D = 2.0 A, R_G = 25 Ω (Note 4)	--	--	30	ns
t_r	Turn-On Rise Time		--	--	80	ns
$t_{d(off)}$	Turn-Off Delay Time		--	--	50	ns
t_f	Turn-Off Fall Time		--	--	70	ns
Q_g	Total Gate Charge	V_{DS} = 560 V, I_D = 2.0 A, V_{GS} = 10 V (Note 4)	--	8.1	11	nC
Q_{gs}	Gate-Source Charge		--	1.7	--	nC
Q_{gd}	Gate-Drain Charge		--	4.4	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain-Source Diode Forward Current		--	--	2.0	A
I_{SM}	Maximum Pulsed Drain-Source Diode Forward Current		--	--	8.0	A
V_{SD}	Drain-Source Diode Forward Voltage	V_{GS} = 0 V, I_S = 2.0 A	--	--	1.4	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, I_S = 2.0 A, dI_F / dt = 100 A/μs	--	260	--	ns
Q_{rr}	Reverse Recovery Charge		--	1.09	--	μC

Notes:

1. Repetitive rating : pulse-width limited by maximum junction temperature.
2. L = 45 mH, I_{AS} = 2.0 A, V_{DD} = 50 V, R_G = 25 Ω, starting T_J = 25°C.
3. $I_{SD} \leq$ 2.0 A, di/dt $\leq$ 200 A/μs, $V_{DD} \leq BV_{DSS}$, starting T_J = 25°C.
4. Essentially independent of operating temperature.

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Typical Characteristics

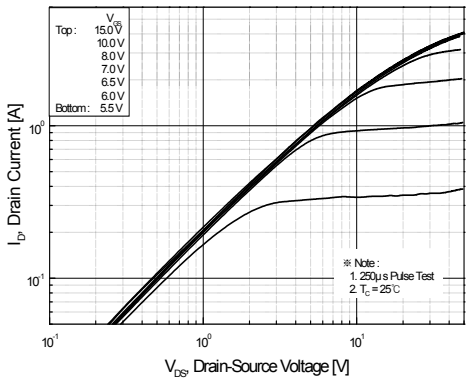

Figure 1. On-Region Characteristics

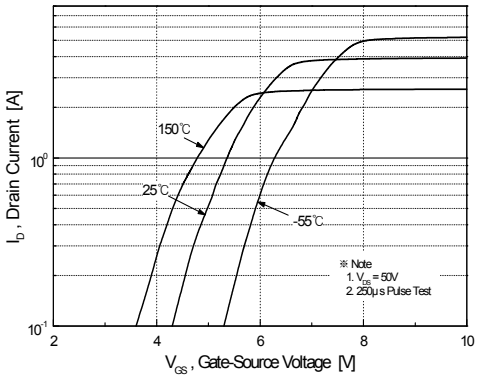

Figure 2. Transfer Characteristics

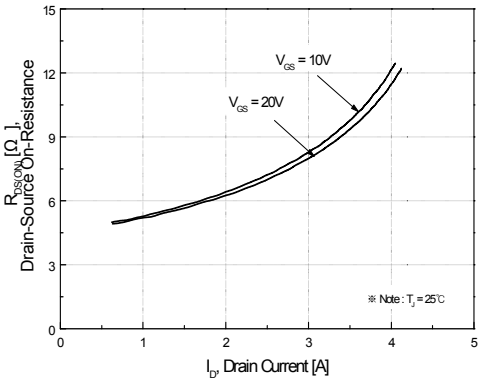

Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

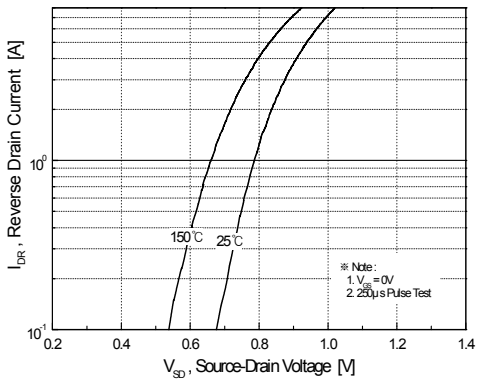

Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

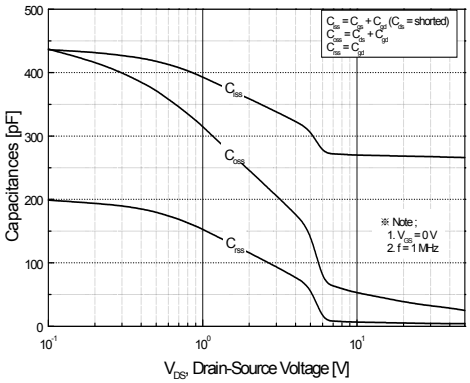

Figure 5. Capacitance Characteristics

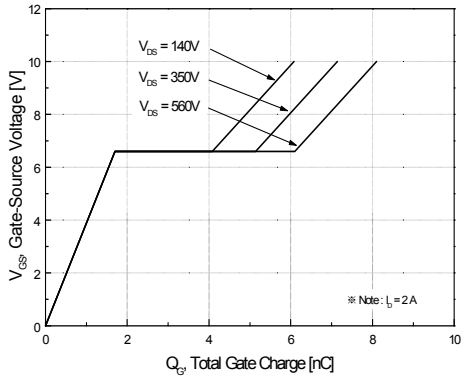

Figure 6. Gate Charge Characteristics

Typical Characteristics (continued)

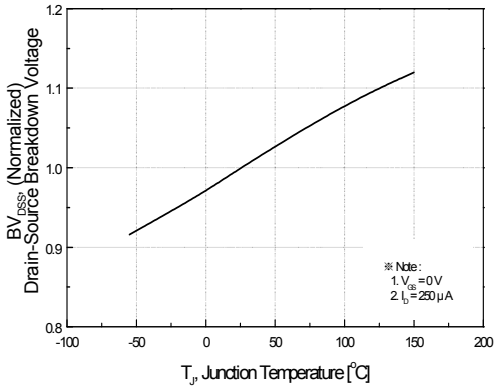

Figure 7. Breakdown Voltage Variation vs. Temperature

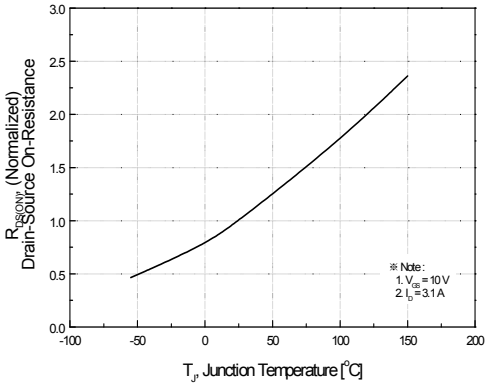

Figure 8. On-Resistance Variation vs. Temperature

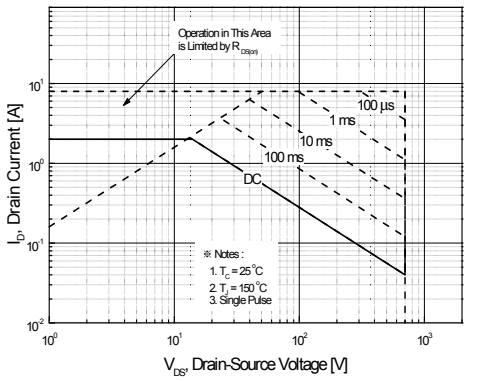

Figure 9. Maximum Safe Operating Area

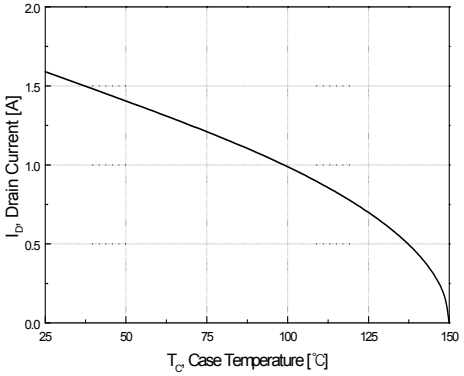

Figure 10. Maximum Drain Current vs. Case Temperature

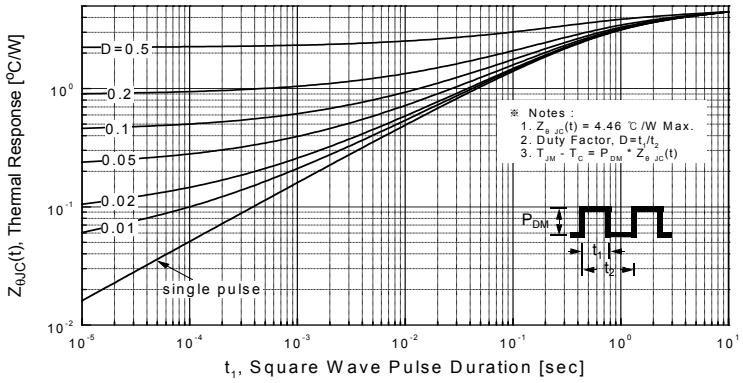

Figure 11. Transient Thermal Response Curve

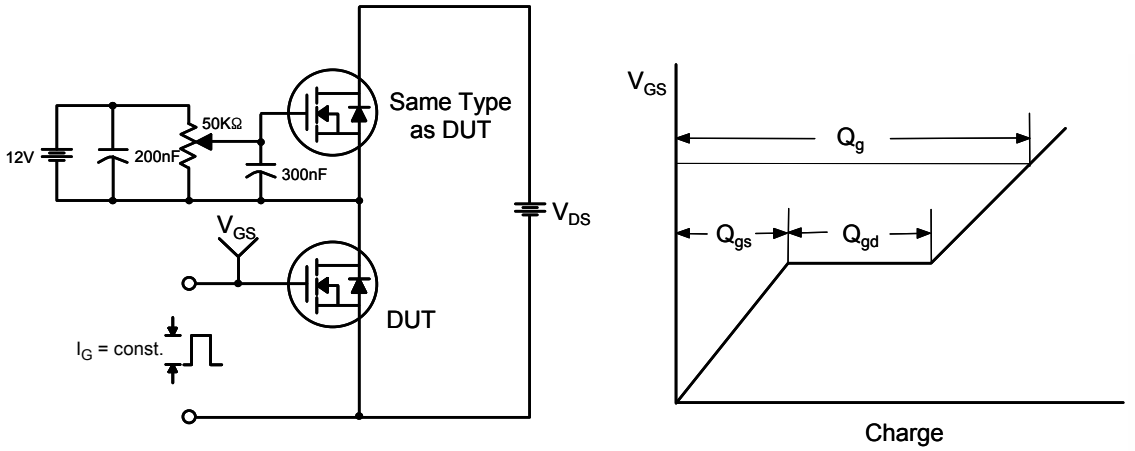

Figure 12. Gate Charge Test Circuit & Waveform

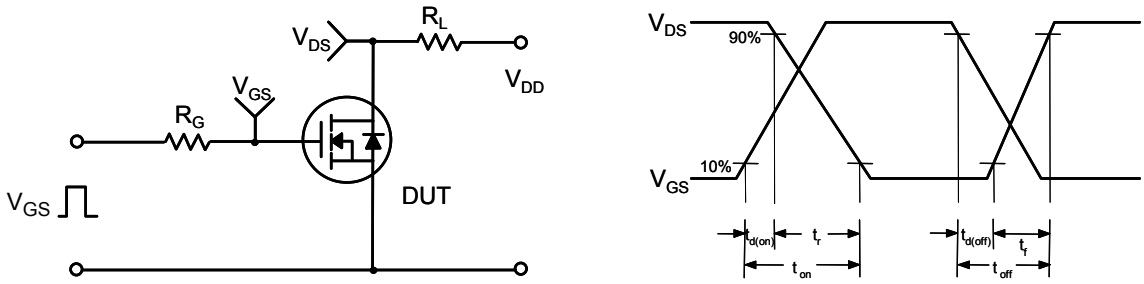

Figure 13. Resistive Switching Test Circuit & Waveforms

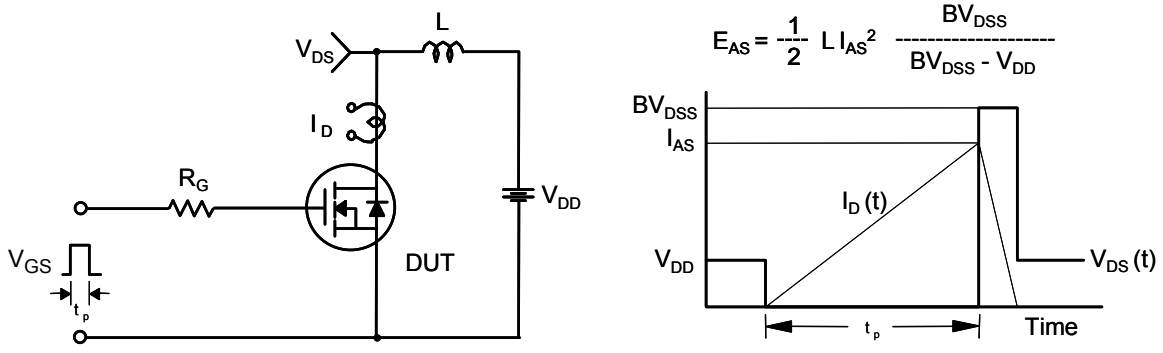

Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

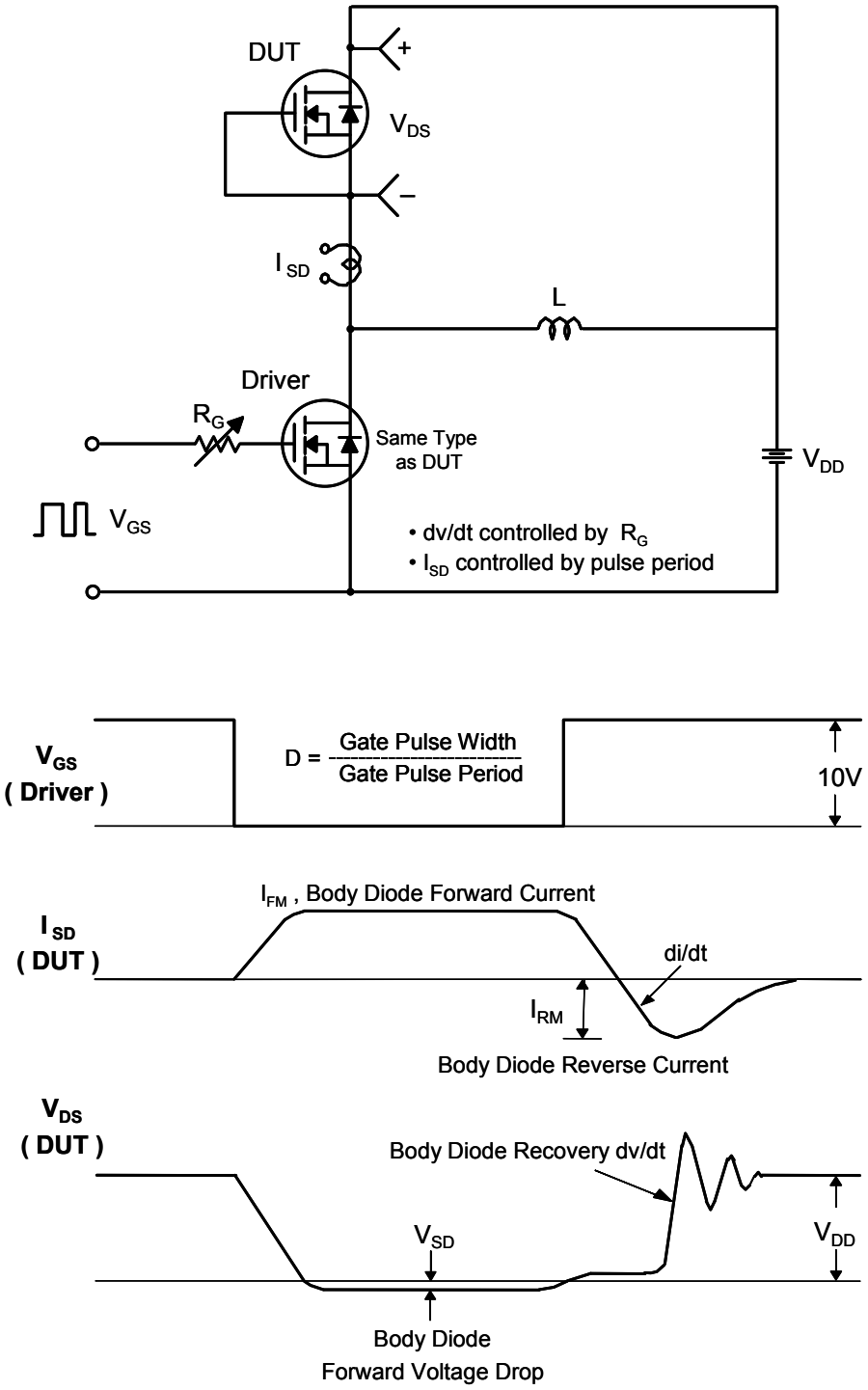

Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

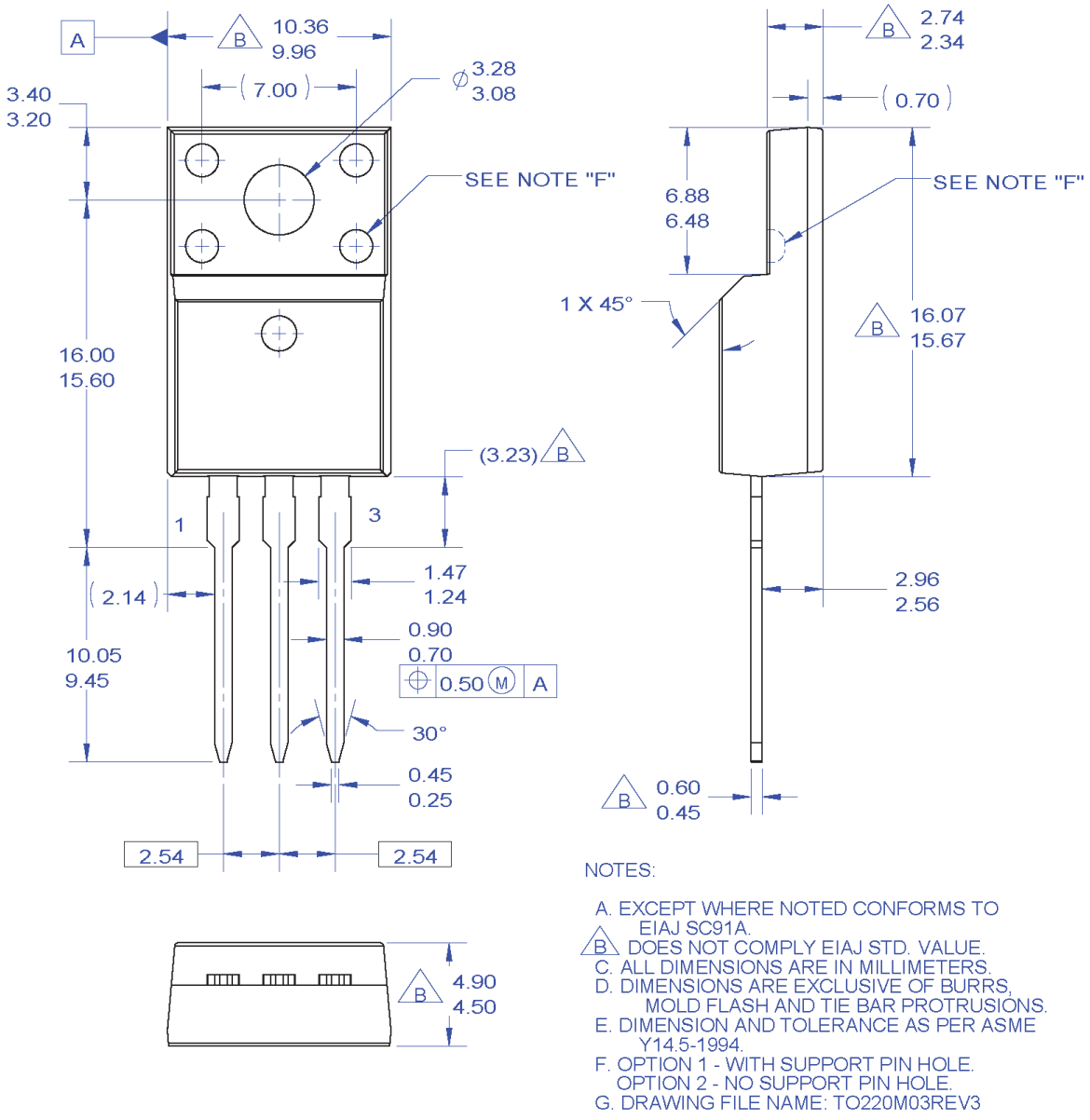

Figure 16. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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